# High Reliability Inverter Initiative

Status Update October, 2004



# Objectives (Additional to Standard)

#### QUALITATIVE

- Reliable
- Long Life
- Rugged

#### QUANTITATIVE

- 15 year warranty
- MTBF of 50 years or more

# Reliable/Long Life/Rugged

- Inherent Weaknesses ٠
  - Defects
  - Aging (FITs)
  - Wearout

**External Forces** 

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- Temperature
- Air density
- Humidity
- Ultra-Violet
- Line and Array
  - Spikes
  - Surges
  - Sags
- Shock/Vibration

- $\blacktriangleright$  µCracks
- ➢ Metal Migration
- Diffusion, Filamentation
- Crystallization

- **Examples**
- > Plasticizers
- $\blacktriangleright$  Conductive Condensation  $\triangleright$  Thermal Shock  $\rightarrow$  Cracks
- Device Stress

- **Internal Forces** •
  - Power $\rightarrow$ Temperature
  - dP/dt (thermal shock)
  - V, I
  - dI/dt, dV/dt
  - Aging Mechanisms

- ➢ Fatigue due to Cycling

### Focus of Initiative

- Eliminate if Possible
  - Unreliable parts
  - Parts with pronounced Wearout
- Mitigate/Minimize Environmental Stress
- Minimize Dissipation, Maximize Heat Transfer
- Rugged Array and Grid Interface, Rugged Packaging
- Transition to Manufacturing critical (Design for Manufacturing, DFM)
  - Parts Qualification and Handling
  - Design Rules

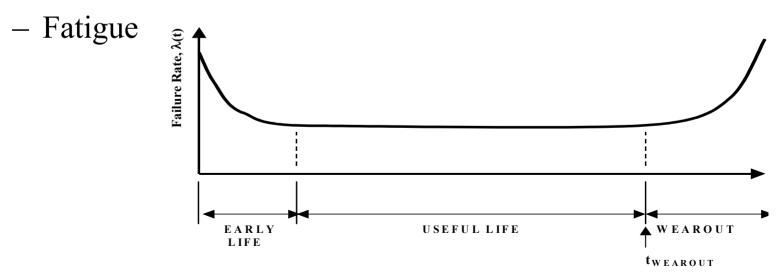
#### FITs - Temperature is Critical

- Ambient Temperature
- $\Delta T$  (Power,  $R_{TH}$ )
- Cycling

$$MTBF = \frac{1 \times 10e9}{\sum_{i=1}^{n} q_{i} \times r_{i}}$$

 $r_i$  = Failure in Time (FIT)

- Cracking, crack propagation
- Flexing, shear stress at interface (expansion mismatch)



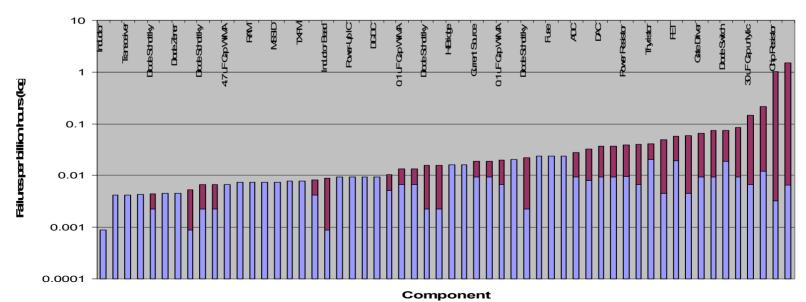
#### Squeeze Reliability into Design by Reducing FITs

- Reduce Stresses (derate) [Minimize Dissipation First]
- Reduce Component Count
- Eliminate Components
- Alternative Technology

Arrhenius

 $k = A * exp^{(-E_a/R*T)}$ 

 $E_a-Activation \ Energy$ 



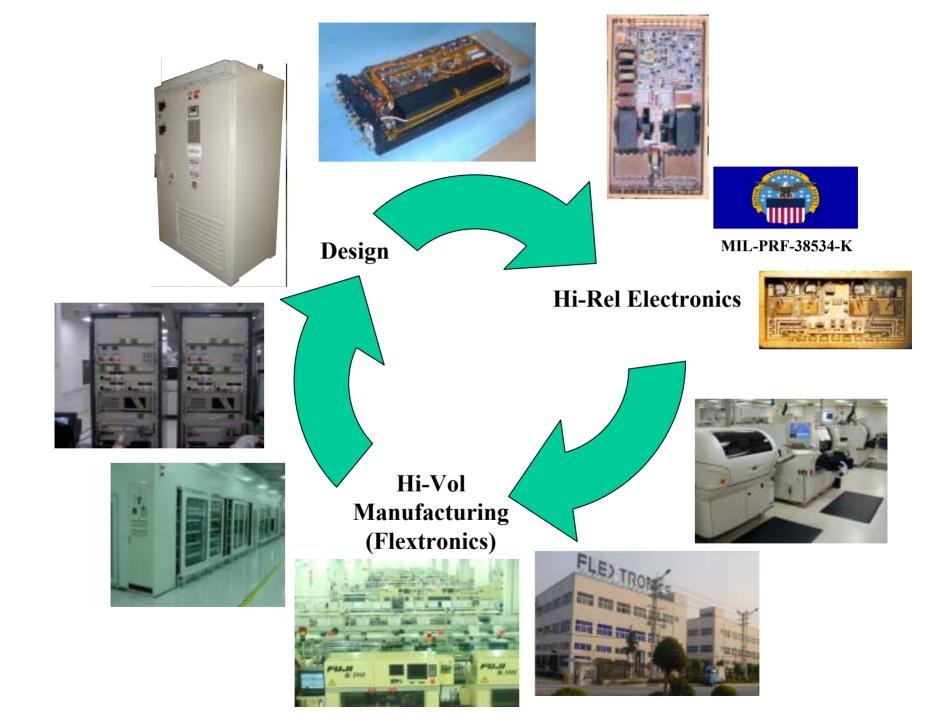
Total Failure Rate/ Component Failure Rate

# Typical Parts Derating

COMPONENT	APPLIED VOLTAGE	POWER	MAXIMUM TEMPERATURE
Film Resistors, Thermistors	80% rated	75% rated	125°C (150°C rated)
Metal Sense Resistors	N/A	75% rated	125°C (170°C rated)
Power Semiconductors	80% rated VGS, BVBEO	Observe temperature derating	125°C (Tj max; 150-175°C rated)
Signal Level Discretes	80% rated (if applicable)	75% Power, forward current, surge current	125°C (Tj max; 150-175°C rated)
Ceramic Capacitors	Continuous: 80% rated Peak: 100% rated	N/A	Self Heating <5°C, (125°C case temp rated)
Tantalum Capacitors	Continuous: 33% rated Peak/reverse: 50% rated	75% of rated ripple current	125°C max case; (170°C Tg)
РСВ	Observe UL spacing for ISO barrier	N/A	120°C (135°C Tg); 125°C (170°C Tg)
Optocouplers	80% rated	75% rated forward current	110°C max case
Linear/Analog	80% rated	80% rated Pdiss	125°C (Tj max)
IC - Logic	80% rated	80% rated Pdiss	125°C (Tj max)
IC - ASIC/uP	80% rated	80% rated Pdiss	125°C (Tj max)
IC - CMOS	80% rated	80% rated Pdiss	125°C (Tj max)
IC - Bipolar	80% rated	80% rated Pdiss	125°C (Tj max)
Fuses	100% rated	80% rated current	75% I <sup>2</sup> t rating

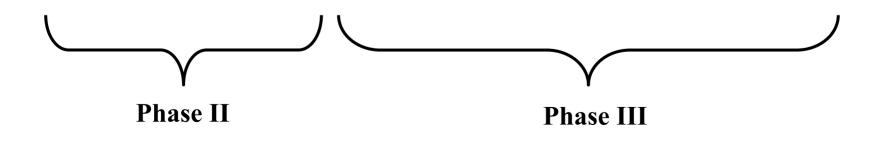
#### System Approach to Increasing Reliability/Service-Life

"Disciplines/Skills/Stages/Phases/"		Impact of Weak Components		
		<b>Ceramic</b> Caps	Electrolytic	
•	Power Circuit Topology		*	
•	Component Life/Reliability	*	*	
•	Control		*	
•	Hardware	*	*	
•	Software		*	
•	Packaging	*	*	
•	Thermal	*	*	
•	Passives (Magnetics/Capacitors)	*	*	
•	Design for Manufacturing	*		
•	Transition to Manufacturing	*		



#### **Project Status**

Concept	Design	PROOF OF	PROOF OF	Manufacturing
Design	Verification	DESIGN	MANUFACTURING	Integration
<ul> <li>Generate electrical specification</li> <li>Review Performance requirements</li> <li>Design Simulation</li> <li>Schematic</li> <li>Qualify new components</li> <li>Breadboard</li> <li>Prelim thermal analysis</li> </ul>	testing • Worst-case	<ul> <li>Build 10 units &amp; electrically characterize</li> <li>Verify electrical performance</li> <li>Verify component stress analysis</li> <li>Statistical variations</li> <li>Thermal management analysis and imaging</li> <li>HALT/HASS testing</li> <li>Complete datasheet</li> </ul>	<ul> <li>25 unit Mfg. run</li> <li>ATE testing</li> <li>Yield analysis</li> <li>Validate and finalize manufacturing processes</li> <li>1000 hour life test</li> <li>Qualification testing (humidity, vibration, DMT, power thermal cycling, thermal and mechanical shock)</li> <li>Certification (UL, FCC,)</li> </ul>	<ul> <li>Processes transfer</li> <li>Full documentation release (SCD's, BOM, processes, procedures, etc.)</li> <li>Release Qualification reports</li> <li>Release final datasheet</li> <li>Transfer units to Finished Goods</li> </ul>



# Future Directions

≻Higher E<sub>a</sub>

- Active Devices
- Passive Devices
- Packaging
- Improved Thermals
- Physical/Electrical Interfaces
- Control (Build on DeadBeat ...)
- Fault Tolerance (Components, Circuits, Systems)
  - Paralleling for robustness and performance

3—5 year horizon

SiC, GaN, ... Nanocrystalline, ... Diamond Like Film, ... Dielectrics, Dry Polymer, ... High T plastics, ...